

Energy Storage Monitoring System and In-Situ Impedance Measurement Modeling

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Overview

Timeline

- Ongoing Project
- Start October 2007

Budget

- Total project funding:
 - DOE 660k (through FY11)
- Funding received in FY11:
 - \$450k
- Funding for FY12:
 - \$400k

Barriers

- Cost
- Performance
- Abuse Tolerance and Reliability
- Life Estimation

Partners

- Montana Tech of the University of Montana
- Qualtech Systems, Inc.



Relevance

Objective:

 Develop advanced in-situ diagnostic and prognostic tools for more accurate prediction of the state-of-health and remaining useful life of energy storage devices.

Benefits:

- Safety and reliability: Rapid identification of failure thresholds
- Cost: Smarter replacement schedules
- <u>Life Estimation</u>: Improved sensor technology for state estimation
- Performance: Improved management systems based on battery condition using both energy and power.

Applications:

- Automotive (EV, HEV, PHEV)
- Military (field radio operations, warehouses, vehicles, etc.)
- Other applications include NASA, electric utilities, telecommunications, aeronautics, consumer electronics, etc.



Relevance (cont.)

Mission Areas:

- Rapid, in-situ impedance spectrum measurement techniques using hardware and control software – <u>Impedance Measurement Box</u>
- Modeling and prognostic tools that smartly combine impedance measurements with other observations to determine a more accurate definition of battery health.
- Hardware and software that directly interfaces with onboard battery technologies to smartly monitor and report health – <u>Energy Storage</u> <u>Monitoring System</u>.

FY-12 Objectives:

- Design and build a 50-V rapid impedance measurement system.
- Improve calibration system of rapid impedance measurement.
- Continue validation studies of rapid impedance measurement techniques using commercially available lithium-ion cells.
- Initiate incorporation of rapid impedance measurements into new and existing modeling and prognostic tools.



Approach

Impedance Measurement Box:

- Develop rapid impedance spectra measurement techniques
- Design low-cost hardware and control software
- Implement measurements under no-load and load conditions

Modeling:

- Equivalent circuit modeling of rapid impedance measurements
- Feature extraction (e.g., effective charge transfer resistance, etc.)
- Estimate pulse resistance and power capability from impedance measurements
- Implement existing modeling capabilities (ES124) to develop prognostic tools for arbitrary aging conditions

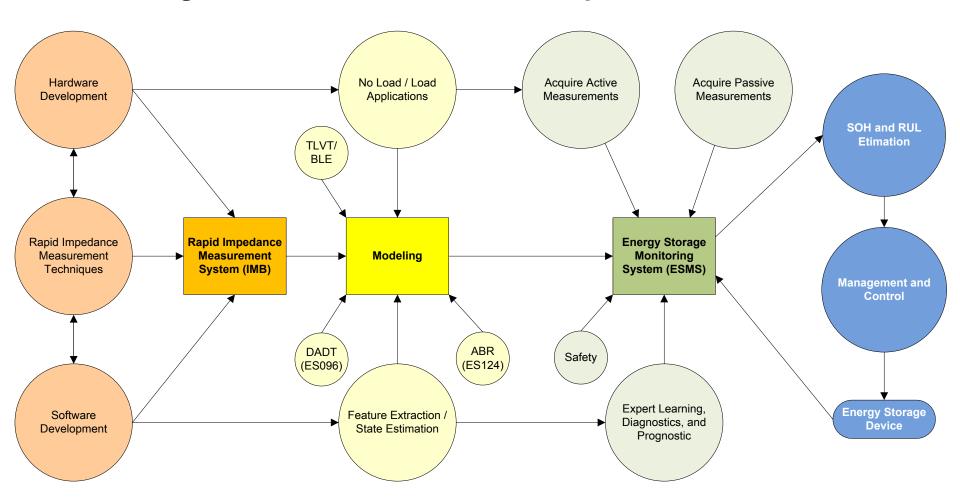
Energy Storage Monitoring System:

- Passive measurements (voltage, current, temperature)
- Active measurements (rapid impedance spectra)
- Incorporate models to estimate overall state-of-health (SOH) and remaining useful life (RUL)



Approach (cont.)

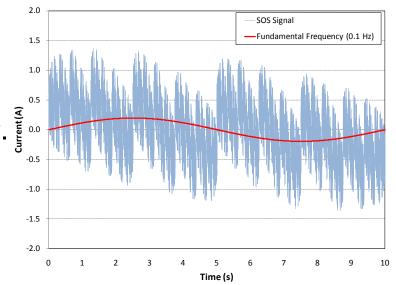
Flow diagram of the overall ESMS concept:





Technical Accomplishments and Progress

- Novel techniques have been developed to acquire wideband impedance within seconds.
 - Harmonic Compensated Synchronous Detection (HCSD)
 - Low resolution, computationally intensive, short test duration
- Input signal is an octave harmonic sum-of-sines excitation current.
 - The excitation signal has a duration of one period of the lowest frequency.
- Synchronously detect the magnitude and phase of the captured voltage response time record.



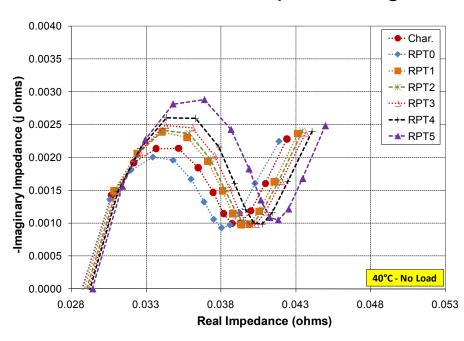
- Long term validation testing was completed using Sanyo SA cells.
 - Cells aged at 40 and 50°C with periodic HCSD measurements under both no-load and load conditions.

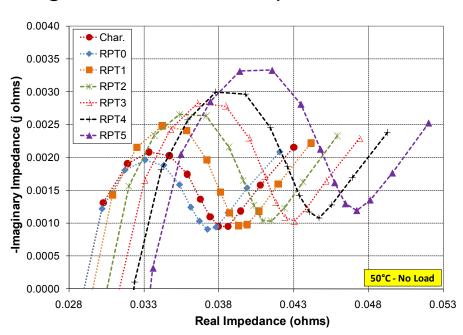




HCSDs under no-load conditions:

- HCSD impedance spectra grow in both ohmic and effective charge transfer resistance.
- The rate of impedance growth is higher at 50°C, as expected.

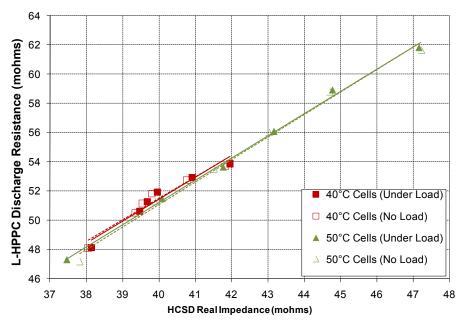


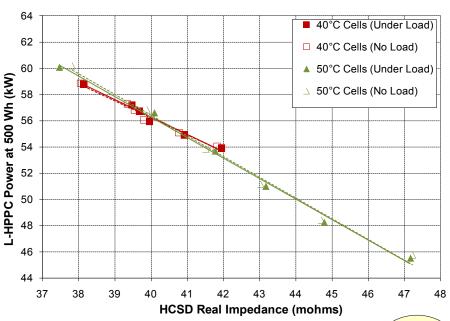




HCSDs under no-load conditions (cont.):

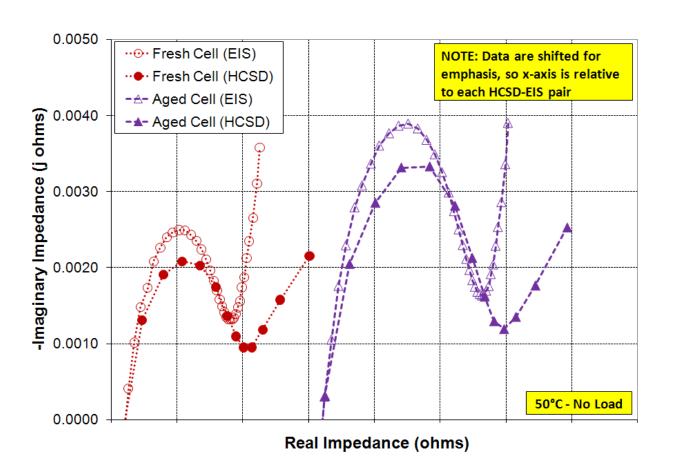
- The HCSD real impedance at the semicircle trough is highly correlated with both HPPC discharge resistance and available power.
- $-r^2 \ge 0.950$ in all cases, most fits are $r^2 \ge 0.980$.







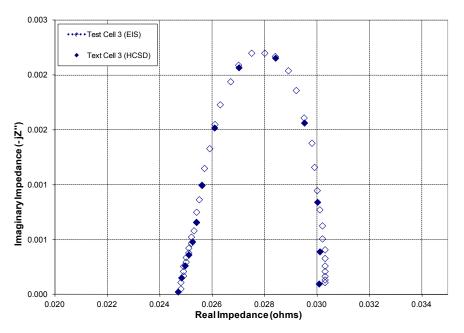
- HCSDs under no-load conditions (cont.):
 - HCSD results generally match standard EIS measurements in the key mid-frequency range.

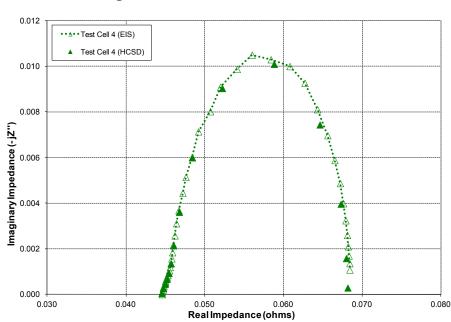


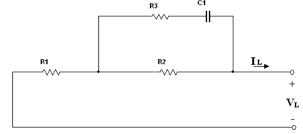




- HCSDs under no-load conditions (cont.):
 - The calibration issue has been resolved and the EIS and HCSD measurements now match very well using test cell circuits.

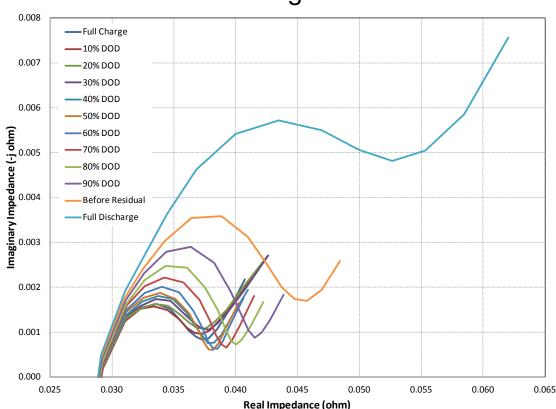








- **HCSDs under no-load conditions (cont.):**
 - A new validation study is now underway with Sanyo SA cells to measure HCSD at multiple DODs.
 - At RPT0, the mid-frequency semicircle generally increases in both height and width with increasing DOD.



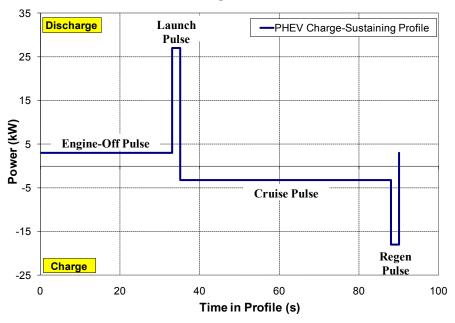


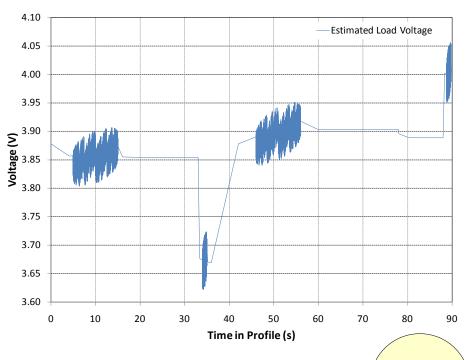
HCSDs under load conditions :

 Cells were cycled at elevated temperatures with HCSD measurements triggered every 50 cycles.

Under-load measurements were affected by a non-constant DC bias voltage

bias voltage.

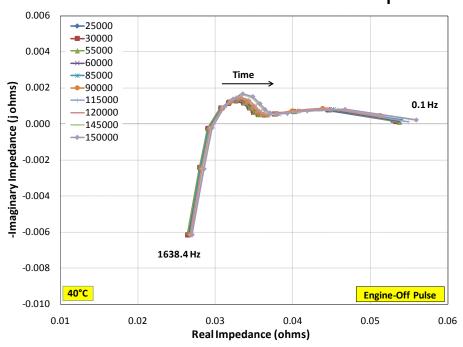


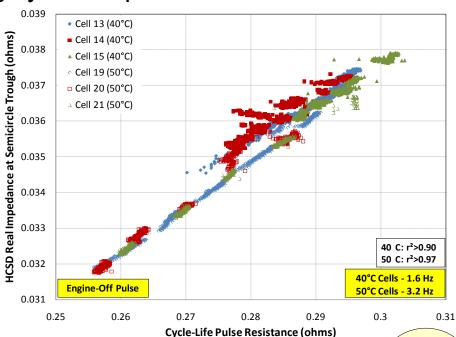




HCSDs under load conditions :

- The Engine-Off impedance measurement under load still shows a mid-frequency arc, but the Warburg tail has flattened out.
- The growth in effective charge transfer resistance is linearly correlated to the corresponding cycle-life pulse resistance.

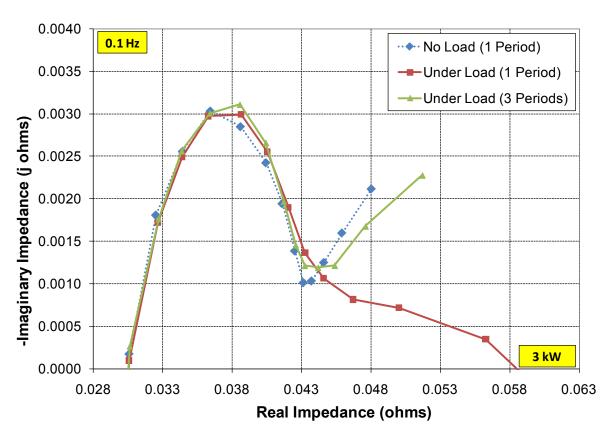






HCSDs under load conditions:

Despite the low-frequency effects, the height and width of the effective charge transfer resistance semicircle is similar under both no load and load conditions.

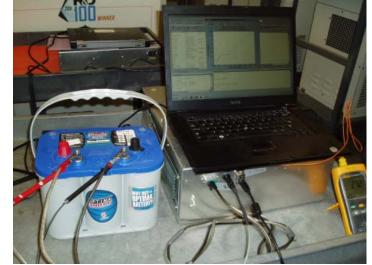




Hardware Development:

 The 50-V Impedance Measurement Box, including prototype hardware and upgraded control software, has now been completed.

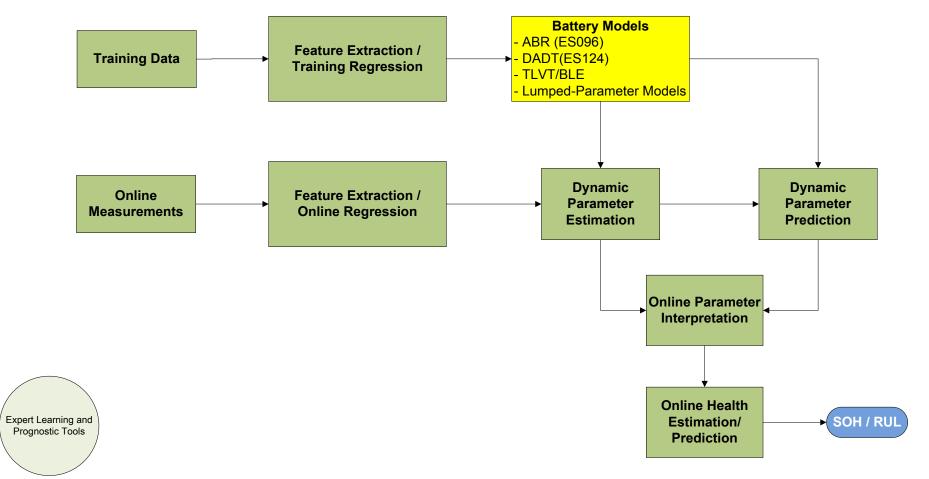
- Upgraded features for this hardware system include:
 - Applied dynamic voltage range between 0 and 50 V (i.e., system can test 5-V cells and 50-V modules)
 - Significantly reduced noise crosstalk in voltage feedback loop when removing the DC bias (up to 50 V)



- Modular design for easier debugging and future upgrades
- Voltage and current probe protection
- Improved calibration technique



- Modeling and State-of-Health Estimation:
 - Preliminary SOH assessment tool under development using results from the HCSD validation studies.





Collaborations

Montana Tech of the University of Montana:

- Expertise in signal processing, hardware design
- A professor and several graduate students have been involved in this effort.

Qualtech Systems, Inc.:

Expertise in software development

Other (future) collaborators:

- Agreement for a developmental collaboration between INL and the Army (CERDEC) is being drafted.
- Various discussions with private industry about IMB/ESMS applications are also underway.



Proposed Future Work

Impedance Measurement Box:

- Investigate possibility of lower frequency measurements while still retaining fast measurement speeds.
- Mitigate observed transient effects and bias voltage error for under-load measurements.

Modeling:

- Develop dynamic parameter estimation and prediction tools for online prognostics at arbitrary aging conditions.
 - Feature extraction from impedance spectra
 - New and existing modeling tools (e.g., ES124)
- Continue validation testing for enhanced modeling capability.

Energy Storage Monitoring System:

- Explore low-cost hardware solutions for embedded system applications.
- Seek collaborative opportunities with other groups involved in battery prognostics and control.



Summary

- The Impedance Measurement Box (IMB) enables low-cost, rapid, in-situ impedance spectra measurements.
 - The IMB addresses cost, safety, performance, and life estimation barriers for energy storage devices.
- Significant IMB accomplishments:
 - The 50-V Gen 3 IMB hardware design has been completed.
 - Improved calibration techniques have been implemented for more accurate impedance measurements.
 - Initial validation study is complete and a new study is underway with rapid impedance measurements at multiple DODs.
- A preliminary state-of-health assessment architecture design has been developed.
 - Dynamic parameter estimation and prediction rely extensively on battery modeling capability and training regression tools



TECHNICAL BACK-UP SLIDES



Impedance Measurement Box

- Novel techniques have been developed to acquire wideband impedance within seconds:
 - Impedance Noise Identification (INI)
 - Very high resolution, computationally very intensive, very long test duration
 - Compensated Synchronous Detection (CSD)
 - Lower resolution, computationally intensive, long test duration
 - Harmonic Compensated Synchronous Detection (HCSD)
 - Low resolution, computationally intensive, short test duration
 - Fast Summation Transformation (FST)
 - Low resolution, computationally simple, short test duration
 - Cross-Talk Compensation (CTC)
 - High resolution, computationally intensive, short test duration
- INL, Montana Tech, and Qualtech Systems Inc. collaborated on the development of these techniques.



HCSD Validation Testing

- Purpose of the initial HCSD validation tests:
 - Demonstrate the effectiveness of the rapid impedance spectra measurement technique under both no-load and load conditions using Sanyo SA cells.
- Cells aged at 40 and 50°C for 150,000 cycles with periodic reference performance tests (RPTs) to gauge degradation.
- HCSD measurements under no-load conditions conducted on all cells at each RPT.
- HCSD measurements under load conditions conducted on some cells during cycling.
 - Designated cells were subjected to a total of 10,000 HCSD measurements under load with no obvious signs of additional degradation.



Sanyo SA Cells

- Chemistry:
 - Li(Mn, Co, Ni)O₂ + Li-Mn-O spinel / Graphite
- Rated Capacity:
 - 1.2 Ah (C/1 Rate)
- Battery Size Factor:
 - **1400**
- HPPC Voltage Range:
 - Vmax = 4.1 V
 - Vmin = 3.0 V
- USABC Application:
 - Minimum PHEV



Voltage Bias (Under Load)

- The voltage bias profile for HCSD measurements under load can be observed with simulations.
- A bias voltage remains once the DC term is removed and it affects the measured spectra, especially at low frequencies.

